

SANTA ANA, CA

SCOTTSDALE, AZ For more information call: (602) 941-6300

MSV101A thru **MSV101G** and MSV201A thru **MSV701A**

Features

The MSV series consists of a matched set of silicon junctions configured for bidirectional application. They can be used in telephone equipment, replacing: copper oxide varistors, fractional voltage regulators, negative temperature coefficient resistors, signal limiters and expanders. They are ideally suited for: meter/galvanometer protection, wave shaping, threshold limiters and zener diode compensation.

The MSV varistor uses two anti-parallel, matched, silicon diodes in a twoelectrode device configuration with a voltage-dependent nonlinear resistance that drops markedly as the applied voltage is increased.

MSV devices are designed for controlled protection at various current levels and are rated at various peak pulse currents.

These varistors are supplied in Microsemi's cost-effective, highly reliable, molded axial leaded package. Non-standard voltages are available. Devices in this series with V_{C2} clamping are rated to U.L.497B requirements. (See table.)

Maximum Ratings

Steady State Power: 1.0 Watt at 50°C

Operating and Storage Temperatures: -65°C to +175°C

Surge: 30 Amps, 8.4 ms @ 25°C

Pulse: 1.0 ms @ 25°C for V_{C1} clamping* $t_{clamping}$ (0 volts to V_{BR} min.): less than 1x10-8 seconds (theoretical)

Electrical Characteristics at 25°C (Test Both Polarities)

| MICROSEMI PART NUMBER | VBR at IBR Vdc / µA Minimum | V _{BR} at I _{BR} Vdc / mAdc Maximum | V _{CI} at Ipp+ V / A Maximum | C _J at zero volts f = 1 MHz pF Maximum | V _{C2} ** V Maximum |
|-----------------------------|---|---|---|---|------------------------------------|
| MSV101A | .05 / 10 .14 / 100 | .51 / 1,000 | - | 200 | - |
| MSV101B | .u5 / 10 .14 / 100 | .66 / 1,000 | | 200 | - |
| MSV101C | .05 / 10 .14 / 100 | .50 / 1,000 | <u>:</u> . | 200 | |
| MSV101D | .43 / 100 .56 / 1,000 | .72 / 10 | 1.5 / 50 | 1500 | 3.8 |
| MSV101E | .43 / 100 .56 / 1,000 | .90 / 100 | 1.5 / 50 | 1500 | 3.8 |
| MSV101F | .20 / 10 .56 / 1,000 | .90 / 100 | 1.5 / 50 | 1500 | 3.8 |
| MSV101G | .20 / 10 .56 / 1,000 | .90 / 100 | 1.5 / 50 | 1500 | 3.8 |
| MSV201A | .86 / 100 1.10 / 1,000 | 1.48 / 10 | 3.0 / 45 | 750 | 4.4 |
| MSV301A | 1.60 / 1,000 | 2.40 / 50 | 4.5 / 40 | 500 | 5.4 |
| MSV401A | 1.72 / 100 2.20 / 1,000 | 2.92 / 10 | 4.5 / 35 | 400 | 6.4 |
| MSV401B | 1.30 / 10 2.20 / 1,000 | 2.92 / 10 | 5.5 / 35 | 400 | 6.4 |
| MSV401C | 2.20 / 1,000 | 3.10 / 50 | 5.5 / 35 | 400 | 6.4 |
| MSV501A | 1.70 / 10 2.80 / 1,000 | 5.00 / 100 | 6.5 / 30 | 300 | 7.4 |
| MSV601A | 3.00 / 100 3.40 / 1,000 | 4.60 / 100 | 8.0 / 30 | 250 | 8.4 |
| MSV701A | 3.70 / 100 3.90 / 1,000 | 5.00 / 5.0 | 9.0 / 30 | 220 | 9.4 |

^{*} Conditions: Pulse is 10 x 1000 µs waveshape

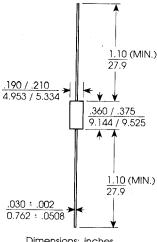
- Voltage limits measured at Ipp peak pulse current.

BIDIRECTIONAL **VARISTORS**

SCHEMATIC



PACKAGE DIMENSIONS



Dimensions: inches

Mechanical Characteristics

CASE: Void free molded thermosetting plastic.

FINISH: Plated CCFE readily

solderable.

POLARITY: Bidirectional.

WEIGHT: 1.5 gram (Appx.)

MOUNTING POSITION:

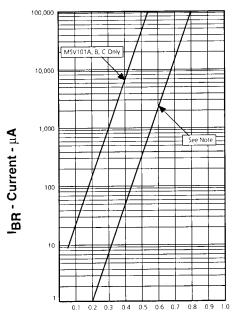
Any.

** Per U.L.497B with 100v / µs rise time.

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^{- 10} µs rise, 1000 µs triangle fall to 1/2 amplitude.

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V_{BR} - Voltage - Volts

FIGURE 1

Typical Current versus Voltage †

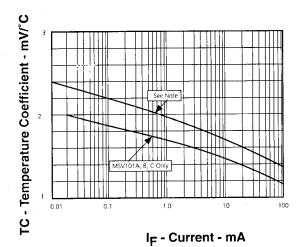


FIGURE 2

Temperature Coefficient of Voltage vs. Current †

(NOTE: TC is a negative value.)

† NOTE: Multiply applicable V_{BR} voltage or TC by 2 for MSV201, by 3 for MSV301, by 4 for MSV401, by 5 for MSV501, by 6 for MSV601, and by 7 for MSV701.